

Product data sheet

1. General description

AC Thyristor Triac power switch in a TO220 plastic package with self-protective clamping capabilities against low and high energy transients.

2. Features and benefits

- Clamping structure ensuring safe high over-voltage withstand capability
- High junction operating temperature capability
- Full cycle AC conduction
- · Over-voltage withstand capability to IEC 61000-4-5
- Pin compatible with standard triacs
- Planar passivated for voltage ruggedness and reliability
- Protective self turn-on capability for high energy transients
- Safe clamping capability for low energy over-voltage transients
- Less sensitive gate for high noise immunity
- Triggering in three quadrants only
- Very high immunity to false turn-on by dV/dt

3. Applications

- AC fan, pump and compressor controls
- Highly inductive, resistive and safety loads
- Large and small appliances (White Goods)
- Reversing induction motor controls

4. Quick reference data

Table 1. Q	uick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	-	800	V
$I_{T(RMS)}$	RMS on-state current	full sine wave; T _{mb} ≤ 120 °C; <u>Fig. 1;</u> <u>Fig. 2</u> ; <u>Fig. 3</u>	-	-	12	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4; Fig. 5</u>	-	-	120	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	-	132	А
Tj	junction temperature		-	-	150	°C
V _{PP}	peak pulse voltage	T _j = 25 °C; non-repetitive, off-state; <u>Fig. 6</u>	-	-	2	kV
Static ch	aracteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 100 mA; LD+ G+; T _j = 25 °C; <u>Fig. 8</u>	-	-	35	mA
		V _D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	35	mA
		V _D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	35	mA

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 10</u>	-	-	50	mA
V _T	on-state voltage	I _T = 17 A; T _j = 25 °C; <u>Fig. 11</u>	-	1.25	1.5	V
V _{CL}	clamping voltage	I_{CL} = 0.1 mA; t_p = 1 ms; T_j = 25 °C	850	-	-	V
Dynamic	characteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	500	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	$ V_{\rm D} = 400 \text{ V}; \text{T}_{\rm j} = 150 \ ^{\circ}\text{C}; \text{I}_{\text{T(RMS)}} = 12 \text{ A}; \\ $	5	-	-	A/ms

5. Pinning information

Table 2.	Pinning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	СМ	common	mb	LD
2	LD	load	۲ C f	
3	G	gate		G—Ź
mb	LD	mounting base; load		ĊM 003aaf296

6. Ordering information

Table 3. Ordering information Orderable part number **Small packing** Package Package Type number Package Packing Name method quantity version issue date ACTT12-800CT TO220 ACTT12-800CTQ Tube 50 SOT78 13-Jun-2008

7. Marking

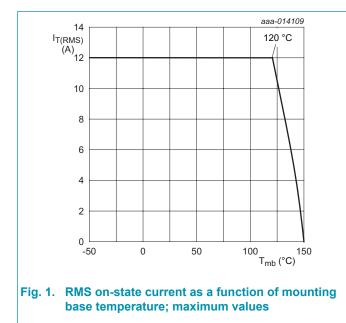
Table 4. Marking codes **Type number Marking codes** Assembly factory: d Assembly factory: A ACTT12-800CT ACTT12 ACTT12 800CT 800CT PJdxxxx xx PJAxxxx xx

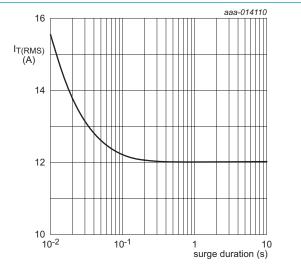
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

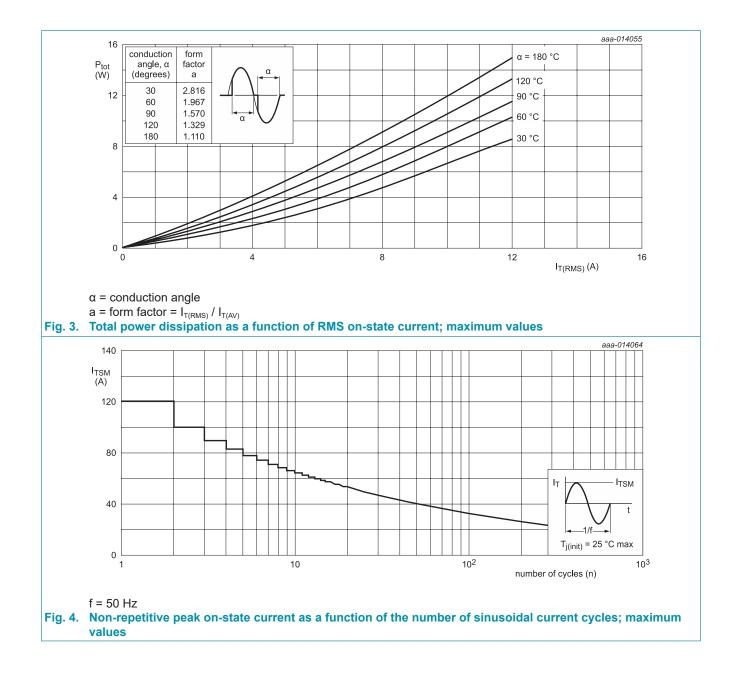
Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 120 °C; <u>Fig. 1;</u> <u>Fig. 2</u> ; <u>Fig. 3</u>	-	12	A
I _{TSM}	non-repetitive peak on-state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4; Fig. 5</u>	-	120	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	132	А
l ² t	l ² t for fusing	t_p = 10 ms; sine-wave pulse	-	72	A ² s
dl _⊤ /dt	rate of rise of on-state current	I _G = 0.2 A	-	100	A/µs
I _{GM}	peak gate current	t _p = 20 μs	-	2	А
P _{GM}	peak gate power		-	5	W
$P_{G(AV)}$	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C
V _{PP}	peak pulse voltage	T _j = 25 °C; non-repetitive, off-state; <u>Fig. 6</u>	-	2	kV

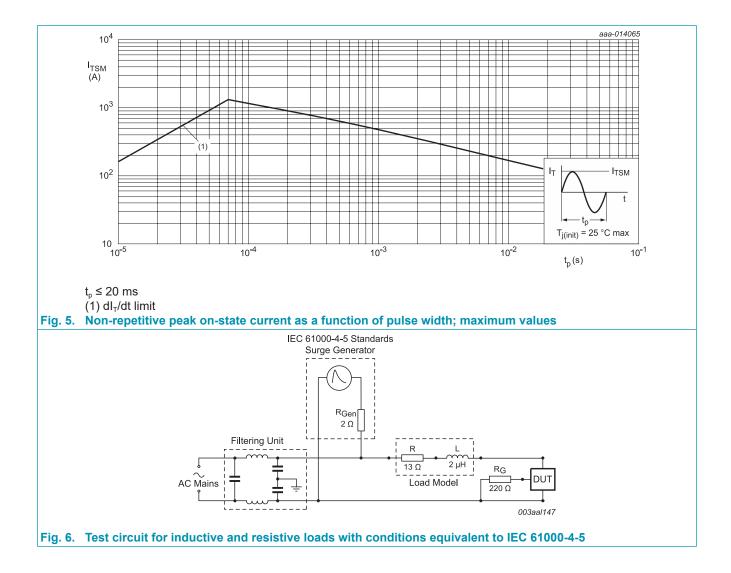






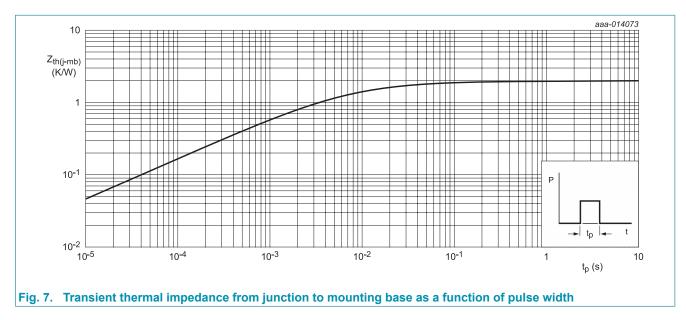
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9. Thermal characteristics

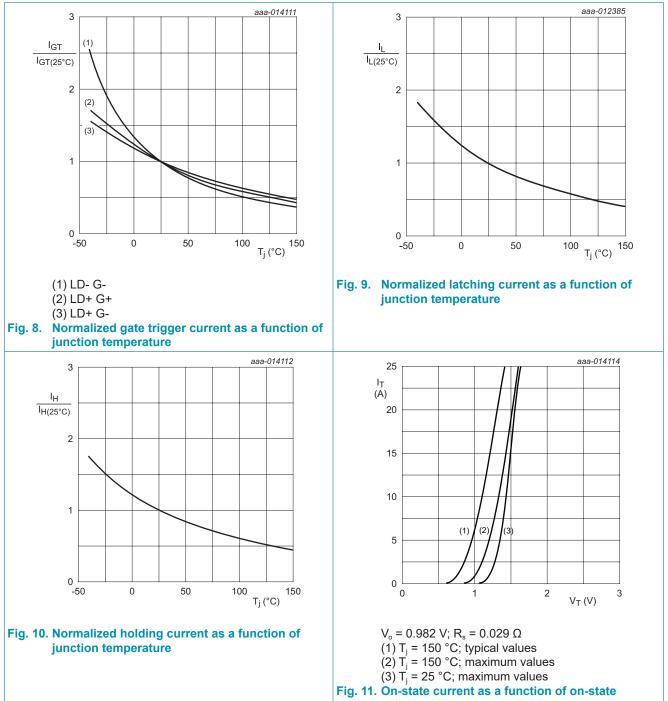
Table 6. Thermal characteristics								
Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
$R_{\text{th(j-mb)}}$	thermal resistance from junction to mounting base	full cycle; <u>Fig. 7</u>		-	-	2	K/W	
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient	in free air		-	60	-	K/W	



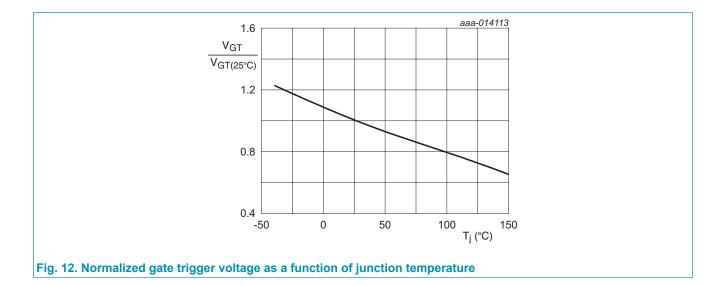
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
I _{GT}	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 100 \text{ mA}; \text{ LD+ G+};$ $T_{j} = 25 \text{ °C}; \text{ Fig. 8}$	-	-	35	mA
		$V_{\rm D}$ = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; Fig. 8	-	-	35	mA
		$V_{\rm D}$ = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; Fig. 8	-	-	35	mA
I _L	latching current	$V_{\rm D}$ = 12 V; I _G = 100 mA; LD+ G+; T _j = 25 °C; <u>Fig. 9</u>	-	-	50	mA
		$V_{\rm D}$ = 12 V; I _G = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 9</u>	-	-	70	mA
		$V_{\rm D}$ = 12 V; I _G = 100 mA; LD- G-; T _j = 25 °C; Fig. 9	-	-	50	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 10</u>	-	-	50	mA
V _T	on-state voltage	I _T = 17 A; T _j = 25 °C; <u>Fig. 11</u>	-	1.25	1.5	V
V_{GT}	gate trigger voltage	V_{D} = 12 V; I _T = 100 mA; T _j = 25 °C; Fig. 12	-	0.8	1	V
		$V_{\rm D}$ = 400 V; I _T = 100 mA; T _j = 150 °C	0.2	0.45	-	V
I _D	off-state current	V _D = 800 V; T _j = 25 °C	-	-	10	μA
		V _D = 800 V; T _j = 150 °C	-	-	2	mA
V _{CL}	clamping voltage	$I_{CL} = 0.1 \text{ mA}; t_p = 1 \text{ ms}; T_j = 25 \text{ °C}$	850	-	-	V
Dynamic	characteristics	· · · · · ·				
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	500	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 150 \text{ °C}; \text{ I}_{T(RMS)} = 12 \text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu \text{s}; \text{ (snubberless condition); gate open circuit}$	5	-	-	A/ms

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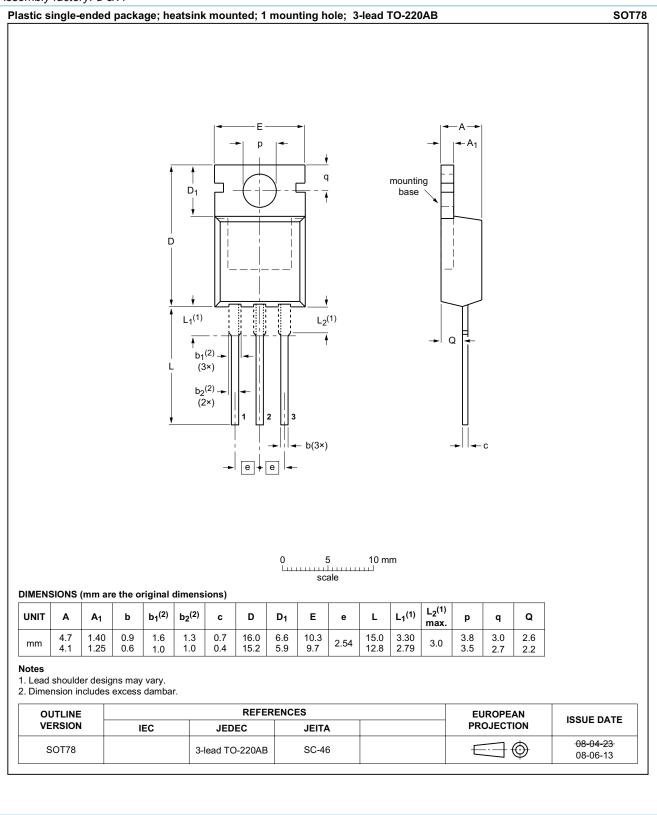


voltage



11. Package outline

Assembly factory: d & A



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12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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